

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	14881	semiconductor and (gan or (gallium adj nitride))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/23 16:55
L2	10662	1 and ((light adj emitting) or laser)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/23 16:55
L3	5987	2 and contact	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/23 16:56
L4	2499	3 and ((quantum adj well) or qw or mqw)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/23 16:56
L5	1807	4 and clad\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/23 16:57
L6	1535	5 and electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/23 16:57
L7	245	6 and (uneven\$4 or roughen\$3) and surface	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/23 16:57

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	5947	(257/13,79,94,95,99,103).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/07/23 17:36